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Magnetron Sputtered Electron Blocking Layer as an Efficient Method to Improve Dye-Sensitized Solar Cell Performance

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Abstract: The main efficiency loss is caused by an intensive recombination process at the interface of fluorine-doped tin oxide (FTO) and electrolyte in dye-sensitized solar cells. Electrons from the photoanode can be injected back to the redox electrolyte and, thus, can reduce the short circuit current. To avoid this, the effect of the electron blocking layer (EBL) was studied. An additional thin film of magnetron sputtered TiO₂ was deposited directly onto the FTO glass. The obtained EBL was characterized by atomic force microscopy, scanning electron microscopy, optical profilometry, energy dispersive spectroscopy, Raman spectroscopy and UV-VIS-NIR spectrophotometry. The results of the current–voltage characteristics showed that both the short circuit current (I_{sc}) and fill factor (FF) increased. Compared to traditional dye-sensitized solar cell (DSSC) architecture, the power conversion efficiency (η) increased from 4.67% to 6.07% for samples with a 7×7 mm² active area and from 2.62% to 3.06% for those with an area of 7×80 mm².

Keywords: photovoltaics; solar cells; dye-sensitized solar cells; electron blocking layer; magnetron sputtering

1. Introduction

After approximately 30 years of research, dye-sensitized solar cells (DSSCs) have maintained their strong importance among scientific and engineering groups across the world. Many approaches have tried to refine the Grätzel [1] architecture of a dye-sensitized mesoporous titanium oxide layer with an iodine-based electrolyte and platinum counter electrode. A significant increase in efficiency would not have been possible without new dyes, whose absorption spectra better match the spectral distribution of both synthetic [2,3] and natural [4] sunlight. Much work has been devoted to improving electrode performance. New wide bandgap semiconductors with different morphologies (e.g., in nanowires, nanotubes, and nanospheres) have been tested [5]. Various electrolyte formulations have been developed and tested in order to improve DSSC performance, increase their lifetime, and reduce their toxicity [6,7].

Besides chemical stability and technical durability (e.g., a time-dependent decrease in power conversion efficiency (PCE) [8,9] or the leakage of liquid electrolytes due to the unsealing of the cells [10]), some typical physical challenges [11,12] are yet to be solved. A frequently reported mechanism that leads to a decrease in DSSC efficiency is the electron–electrolyte recombination process.

In an ideal model, the photoexcited electrons in dyes are injected into a wide bandgap *n*-type semiconductor layer, typically TiO₂, ZnO or SnO₂, and are then transferred to a fluorine-doped tin oxide (SnO₂:F, FTO) working electrode, while the holes created in the dye are filled by electrons from the triiodide present in the redox electrolyte ($2e^- + I_3^- \rightarrow 3I^-$). Unfortunately, there are several possible paths through which electrons recombine. The most significant of these are recombinations at the TiO₂/electrolyte and FTO/electrolyte interfaces. To challenge these pathways, the concept of the electron blocking layer (EBL) was developed. The role of this layer is to block electrons from being injected back into the electrolyte by providing more preferable transport to the FTO via an appropriate band structure.

The EBL can be set directly on a mesoporous *n*-type semiconductor [13] or on the FTO surface [14]. There are two main conditions that need to be fulfilled. Firstly, the layer must be continuous to prevent FTO contact with the electrolyte, and secondly, the layer has to be thin enough to avoid high ohmic resistance. The latter factor could lower the open circuit voltage (U_{oc}) and short circuit current (I_{sc}) due to a greater probability of recombination from structural defects. The blocking layers deposited on mesoporous TiO₂ are generally represented by wide bandgap isolators, such as Al₂O₃ or HfO₂ [15], Zn₂SnO₄ [16], MgO [17] or doped ZnO [18]. Indeed, it is difficult to produce a continuous layer on a mesoporous structure. CVD methods are the most promising because the reaction gas is able to overlay the whole surface exposed to the gas. However, toxic or hazardous precursors and by-products are often a great complication of this technique. Additionally, the required high temperature (in the range of several hundred degrees Celsius) for the CVD growth process could significantly influence the other layers. Thus, it is much simpler to prepare an electron blocking layer directly onto the planar FTO glass, as shown in Figure 1. As reported by Zhu [19], the dominant recombination process occurs at the substrate/electrolyte interface rather than across the TiO₂ matrix. Numerous methods have been commonly used for EBL compact layer preparation, such as sol-gel [20], chemical vapor deposition [21], spray-coating [22], and electrodeposition [23]. Low-cost depositions are typically considered to be the most promising, but they do not provide a process that is highly repeatable, while the parameters, such as thickness, stoichiometry and purity of the layer, are crucial. Among the many potential techniques, the magnetron sputtering method [24,25] seems to be the best choice because of its simplicity of use and repeatability. It is necessary to choose an appropriate material as an EBL. For instance, SnO₂ [26], ZnO [27] or Nb₂O₅ [28] were recently reported. However, TiO₂ is suggested to be the best EBL due to its low cost, chemical inertness to electrolytes, easy availability, good *n*-type conductivity and matching electronic band structure to the photoanode.

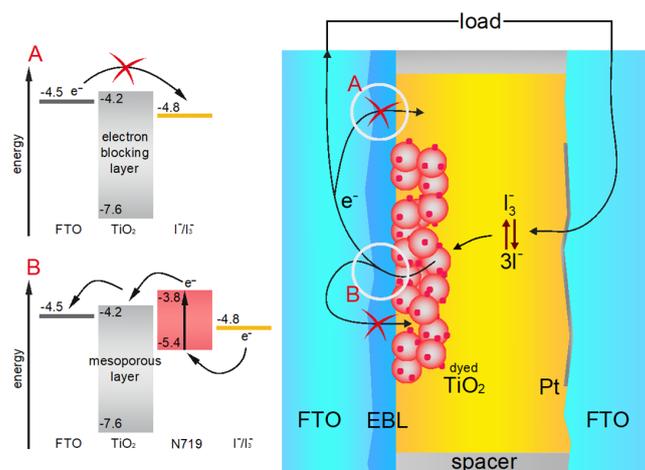


Figure 1. Schematic representation of the fabricated dye-sensitized solar cell (DSSC) devices with an additional electron blocking layer (EBL). As presented in diagram A, the EBL prevents electrons from being injected back from the photoanode to the redox electrolyte, according to the reaction $2e^- + I_3^- \rightarrow 3I^-$. The generation of photocurrent is presented in diagram B.

Herein, a TiO₂ RF magnetron sputtered layer was investigated as an electron blocking layer in screen-printed dye-sensitized solar cells. The results, presented in the following sections, were obtained by the current–voltage characteristics (U–I), scanning electron microscopy (SEM), atomic force microscopy (AFM), optical profilometry (OP), energy dispersion spectroscopy (EDS), Raman spectroscopy (RS) and UV-VIS-NIR spectrophotometry. In this paper, two sizes of the active layer were studied—small- and large-scale solar cells with dimensions 7 × 7 mm² and 7 × 80 mm². The power conversion efficiency, as a result of the additional electron blocking layer, was increased by 30% and 17%, respectively.

2. Materials and Methods

2.1. RF Magnetron Sputtered Electron Blocking Layer Preparation

The TiO₂ compact layer was prepared on the FTO glass (TEC A7, 6–8 Ω/□). The substrates were ultrasonicated in acetone and isopropanol for 5 min and 15 min, respectively. Then, they were transferred to a glove box immediately. The electron blocking layer was sputtered by a Mini SPECTROS™ magnetron system from the TiO₂ target (99.99% pure, Kurt J. Lesker Company®, Jefferson Hills, USA). The chamber was pumped down to about 10^{−5} Torr. A time of 5 min of pre-sputtering was applied to remove any possible contaminants from the target surface. The RF sputtering was carried out at 300 °C to enhance adhesion and, thus, electric contact between the two layers. The parameters of the process were set as a 3 m Torr argon working gas pressure under a power of 100 W. The deposition time was tuned to receive a layer of approximately 30 nm, which was reported as the most efficient thickness for the EBL [29].

2.2. Dye-Sensitized Solar Cell Fabrication

The FTO glass (cleaned as described above) was used to fabricate the working and counter electrodes. Mesoporous TiO₂ film was deposited using the screen printing method [30] from titania paste (18NR-T, Greatcell Solar, Elanora, Australia) and sintered up to 565 °C. The obtained thickness of 11 μm was determined by a stylus profilometer (Bruker DektakXT, Billerica, USA). According to the manufacturer's datasheet, anatase nanoparticles dispersed in the paste have an average size of 20 nm. Samples were immersed for 24 h in a 10^{−4} M ethanolic solution of ruthenium dye (N719, Greatcell Solar, Elanora, Australia) at room temperature. The layers were then rinsed with ethanol to remove the un-adhered molecules. A counter electrode was prepared by the same printing method using a platinum paste (PT1, Greatcell Solar, Elanora, Australia). A 60 μm lamination foil (DuPont Surlyn®, Wilmington, USA) was used to seal both electrodes. The DSSCs were filled with a commercially available iodine-based redox electrolyte (EL-HPE, DyeSol, Elanora, Australia).

3. Results and Discussion

3.1. Measurement of TiO₂ Electron Blocking Layer Thickness

The thickness of the magnetron sputtered nanometric TiO₂ thin film was determined by an optical profilometer (Profil3D, Filmetrics, San Diego, USA) in the white light interferometry (WLI) mode. Before deposition, the edge of the FTO glass was covered by polyimide tape and then removed. Additionally, the taped area was slightly cleaned by isopropyl alcohol to remove any glue residue. Then, the step height was imaged on a profilometer. The received data were used to prepare the height histogram presented in Figure 2. The cyan color represents the bare FTO surface and the olive indicates the FTO covered by TiO₂. The grey area was not included in the calculations because of the irregular layer surface corrupted by detaching the tape. Two Gauss functions were fitted to the obtained peaks. The difference between the peak positions, calculated to be 32.7 nm, was considered as the thickness of the TiO₂ layer.

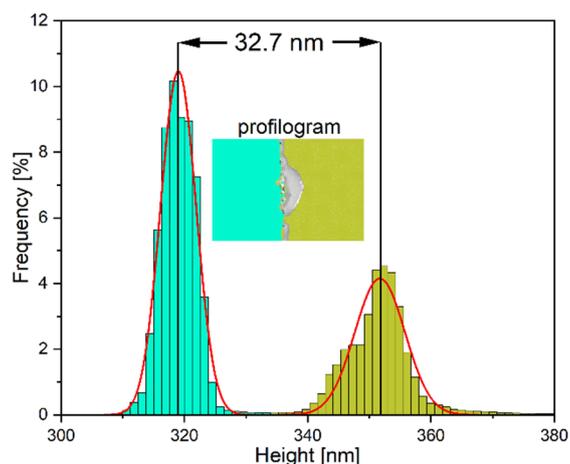


Figure 2. Height histograms received from the TiO₂ step, imaged by an optical profilometer. Bare FTO surface is represent by the cyan color and the thin film of TiO₂ is indicated by the olive color. The difference between the Gauss peak centers determines the layer thickness.

3.2. Energy Dispersive Spectroscopy (EDS) Spectrum

The energy dispersive spectroscopy (SwiftEDS 300, Oxford Instruments, High Wycombe, UK, beam energy 15 kV) outcome, shown in Figure 3, was obtained from a sample with a TiO₂/FTO/glass stack. The signal from the carbon (C) element is a result of the atmospheric adsorption of carbon dioxide because the sample was not heated before its transition to the EDS chamber. The small peak from silicon (Si) came from the glass substrate, which, in fact, is a silica. The observed oxygen (O) signal came simultaneously from the CO₂ adsorbate and the TiO₂, SnO₂:F and SiO_x layers.

Table 1. Characteristic lines received from the EDS spectrum of the TiO₂/FTO/glass stack with energies in keV.

Element	C	O	Si	Sn					Ti		
Line	Kα _{1,2}	Kα _{1,2}	Kα _{1,2}	L1	Lα ₁	Lβ ₁	Lβ ₂	Lγ ₁	Lα _{1,2}	Kα _{1,2}	Kβ _{1,3}
Energy	0.27	0.52	1.74	3.05	3.44	3.67	3.91	4.13	0.39	4.51	4.93

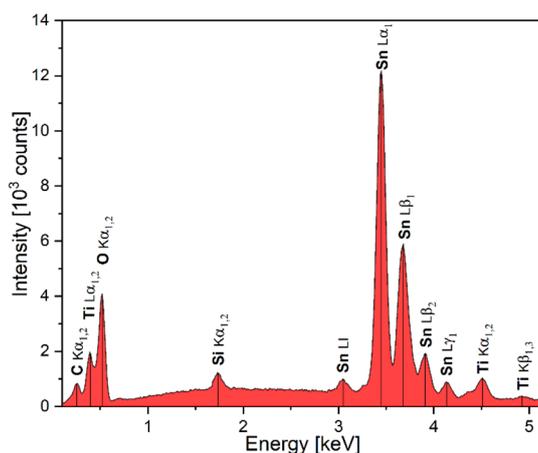


Figure 3. EDS spectrum of the TiO₂/FTO/glass stack. Characteristic lines are tabulated in Table 1.

The broad multippeak signal from tin (Sn) was caused by the FTO’s presence in the analyzed sample. The manufacturer’s datasheet suggests that the FTO film is approximately 250 nm. This significant thickness, compared to the electron penetration depth, explains why the Sn signal has the

greatest importance in the obtained spectrum. The most important piece of information from the received spectrum is that the TiO_2 thin film is present in the sample. This is observable in the three peaks that are tabulated in Table 1. Lines with double numeration are a superposition of two signals with similar energy. For instance, the peaks for O are a superposition of $K\alpha_1$ and $K\alpha_2$ transitions.

3.3. Scanning Electron Microscopy (SEM) and Atomic Force Microscopy (AFM) Images

The electron blocking layer's morphology was studied with a scanning electron microscope (Quanta™ 3D FEG, ThermoFisher Scientific, Hillsboro, USA) before the deposition of the mesoporous TiO_2 . The topography, shown in Figure 4c, is similar to that of the bare FTO, which was also observed by Choi et al. [31]. The reason for this result is the FTO's high roughness. Because of this roughness, covering the FTO with a thin film of material would not significantly influence the RMS parameter. The roughness of the titanium oxide EBL was measured by an atomic force microscope in tapping mode (Agilent 5500, Agilent Technologies, Santa Clara, USA). The RMS decreased slightly from 26.9 nm for the bare FTO to 23.7 nm for a stack of the 30 nm TiO_2 compact layers on the FTO. The intersection, seen in Figure 4a, contains all of the photoanode layers (from the bottom: glass, FTO, TiO_2 compact and TiO_2 mesoporous layers). In reference to the profilometer measurement, the thickness of the mesoporous film was also confirmed to be approximately 11 μm . The morphology of the sintered TiO_2 nanoparticles with an average diameter of 20 nm can be observed in Figure 4b.

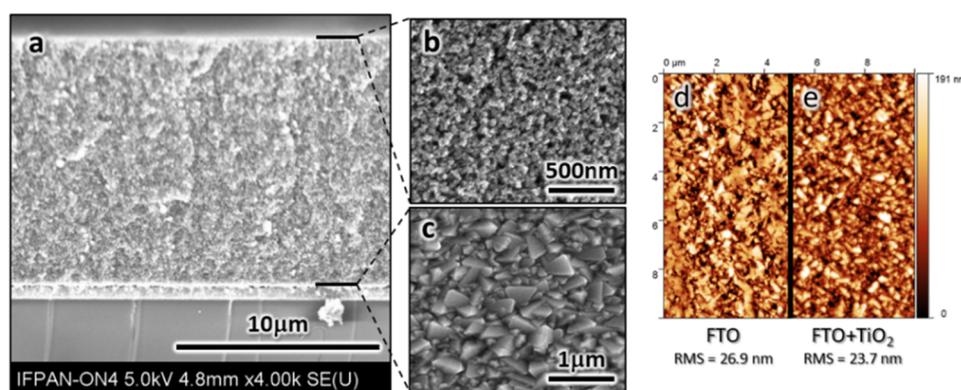


Figure 4. SEM images of (a) the intersection of the photoanode: glass, FTO, TiO_2 compact and 11 μm TiO_2 mesoporous layers, (b) the morphology of the mesoporous TiO_2 film and (c) the TiO_2 compact layer on the FTO. AFM images of (d) the bare FTO and (e) the TiO_2 electron blocking layer on the FTO.

3.4. Raman Spectrum of Electron Blocking Layer

The polymorphism of the titanium oxide electron blocking layer was investigated by Raman spectroscopy. The measurements were made using an integrated Raman spectroscope (LabRAM, HORIBA, Kyoto, Japan). The source used for the measurements was a He–Ne laser with a wavelength of 632.8 nm at 17 mW power. The whole system was complemented by a confocal microscope coupled with an 800 nm focused lens and a two-dimensional multichannel CCD detector. Additionally, the system was equipped with an automatic Czerny–Turner spectrograph with a slot width of 30 mm for a wide–flat field of view. The measurements were taken at room temperature.

According to other studies [32], the obtained spectrum of TiO_2 , shown in Figure 5, was characteristic for anatase. The active vibrations were located at 143 cm^{-1} (E_g), 196 cm^{-1} (E_g), 398 cm^{-1} (B_{1g}), 516 cm^{-1} (A_{1g}) and 639 cm^{-1} (E_g). The provided measurements allowed us to confirm that the TiO_2 mesoporous and TiO_2 electron blocking layer had the same polymorph. The selfsame polymorph should lead to good electric contact after the sintering process under a high temperature because of matching in the conduction bands' levels and the crystal structures of both materials.

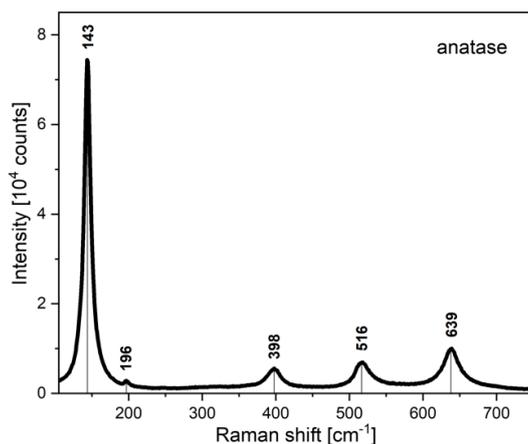


Figure 5. Raman spectrum of the magnetron sputtered TiO₂ electron blocking layer. The observed active vibrations are characteristic of anatase.

3.5. Transmittance and Absorbance Spectra of the Photoanode

Because the light pathway to the dye leads through the whole photoanode, UV-VIS-NIR spectrophotometry (Jasco V-670 with deuterium and halogen lamps) was used to measure the transmittance for each layer. The signal was averaged from a spot size of a $3 \times 3 \text{ mm}^2$ area. Figure 6 presents the transmittance versus the wavelength spectrum of compositions from bare FTO up to FTO covered by a dye-sensitized TiO₂ layer. Just a slight decrease in transmitted light was observed for the additional 30 nm TiO₂ film in the dye absorption wavelength range, which indicates that the EBL layer has no significant influence on the amount of light transmitted to the N719 molecules. Measured absorption peaks near the 390 nm and 530 nm are consistent with those reported by other studies [33,34]. The dye absorbance was measured for a 10^{-4} M ethanolic solution (99.8% ethanol, Honeywell, Charlotte, USA) in a quartz cuvette with 1 cm of optical thickness.

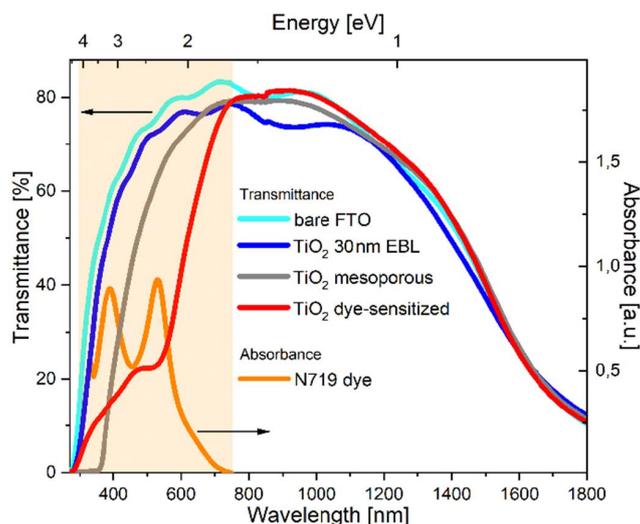


Figure 6. Optical properties of the individual components of the fabricated DSSC photoanode: transmittance spectra of the bare FTO (light blue), TiO₂ 30 nm EBL (navy blue), mesoporous TiO₂ (gray) and mesoporous dye-sensitized TiO₂ (red), compared to the absorbance spectrum of the N719 dye (orange).

3.6. Performance of the DSSC Devices

The performance of the DSSC devices was investigated by a solar simulator (CLASS-01, PV Test Solutions) under AM1.5 illumination with a light intensity of 100 mW/cm^2 . The received current–voltage

(U–I) characteristics are shown in Figure 7. In both cases, the open circuit voltage did not significantly change because the mesoporous and compact TiO₂ layers have similar conduction and valence band levels. Likewise, no difference in U_{oc} was reported by other groups for ZnO and TiO₂ EBLs [35]. Because the main factor for this parameter is the difference between the mesoporous TiO₂ and redox electrolyte energy band levels [36], the *n*-type metal oxide thin film on the FTO should not have a strong effect on the U_{oc}.

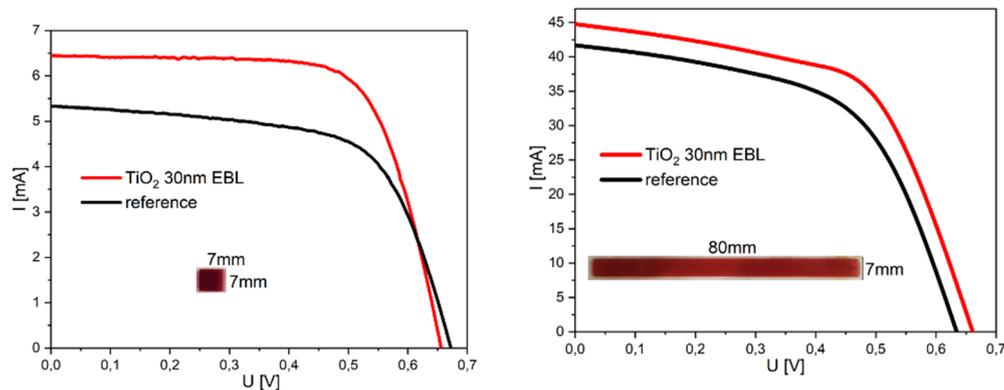


Figure 7. Current–voltage characteristics for $7 \times 7 \text{ mm}^2$ and $7 \times 80 \text{ mm}^2$ DSSC devices with and without a TiO₂ electron blocking layer.

As recently shown, a thin layer of TiO₂ on the FTO electrode significantly increases the onset of cathodic dark current, pointing to the increase in a potential barrier to the electron transfer from the FTO to the electrolyte [37]. In our studies the presence of the electron blocking layer significantly increased the short circuit current (I_{sc}) and, as a consequence, also increased the fill factor (FF). For small samples, an increase from 5.33 mA to 6.44 mA and from 0.64 to 0.70 was observed, respectively. For larger samples, the same parameters increased from 41.67 mA to 44.80 mA and from 0.55 to 0.58, respectively. In both cases, the improvement of those parameters indicates that the recombination process was considerably mitigated. As mentioned above, the power conversion efficiency (η) increased by 30% and 17%, depending on the sample size. Because of the larger surface, there is a higher probability of the electrons being scattered or recombined, especially due to the crystal structure’s defects. The longer path to the electrodes may also cause a relaxation, with incidentally met holes in the FTO. We attempted to mitigate this problem via the preparation of a silver electrode along the active area’s edge. The role of this electrode was to collect the photogenerated electrons, possibly close to the place where they were excited. The measurement errors, presented in Table 2, were calculated by standard deviation. The parameters were obtained from eight samples for every type of DSSC device.

Table 2. DSSC parameters for $7 \times 7 \text{ mm}^2$ and $7 \times 80 \text{ mm}^2$ devices with and without a TiO₂ electron blocking layer.

Sample Size [mm ²]	U _{oc} [V]	I _{sc} [mA]	P _{max} [mW]	FF	η [%]
7 × 7	0.67	5.33	2.29	0.64	4.67
	±0.03	±0.06	±0.05	±0.02	±0.12
7 × 7 with EBL	0.66	6.44	2.97	0.70	6.07
	±0.04	±0.09	±0.05	±0.02	±0.16
7 × 80	0.63	41.67	14.75	0.55	2.62
	±0.04	±2.18	±0.93	±0.05	±0.34
7 × 80 with EBL	0.66	44.80	17.30	0.58	3.06
	±0.04	±2.28	±0.69	±0.04	±0.26

4. Conclusions

A thin film of TiO₂ was studied as an efficient electron blocking layer. Due to its simplicity of use and high repeatability, RF magnetron sputtering was chosen as the deposition method. A 30 nm thick layer was sputtered on bare FTO and then dye-sensitized solar cells were fabricated by a screen printing technique. The UV-VIS-NIR spectrophotometry transmittance spectra showed no significant influence on the amount of light provided through the photoanode to the dye molecules in its absorbance wavelength range. In both cases of the active area (7 × 7 mm² and 7 × 80 mm²), an increase in power conversion efficiency due to decreased recombination (and thus an increased short circuit current) was reported. Because of the larger area, the cross section of recombination for mechanisms other than the FTO/electrolyte interface has greater importance. Thus, the percentage growth of efficiency was higher for small samples (30%) than for larger ones (17%).

DSSCs, as third generation solar cells, provide a great opportunity to serve as low-cost and common photovoltaics and could displace silicon-based devices. Present and future works will certainly improve both the efficiency and stability of DSSCs. However, there are still many physical, chemical and technical problems that need to be resolved to deploy these devices into line production and distribute them to private consumers.

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